Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.050 inches
Overall Diameter:
0.055 inches
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
8.0 working peak reverse voltage
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
100.0 milliwatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
0.25
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air

Precious Material And Location:

Plated leads gold

Precious Material:

Gold

Test Data Document:

82577-925196 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0